

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

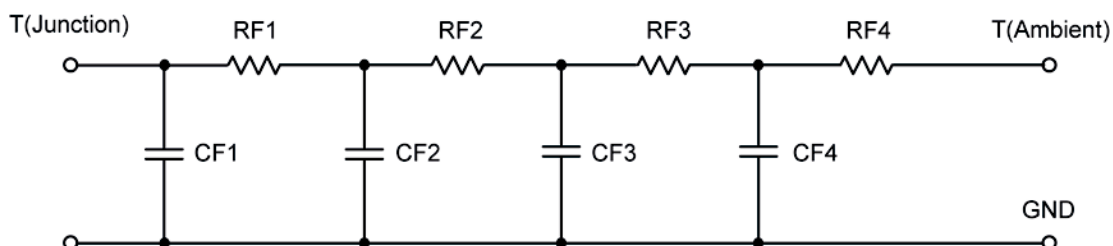
For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	7.6192	N/A	8.3931
RT2	14.4919	N/A	1.2560
RT3	12.1471	N/A	5.7231
RT4	50.5078	N/A	7.6457
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	6.6102 m	N/A	57.9389 m
CT2	199.8001 m	N/A	3.3945 m
CT3	63.9275 m	N/A	6.8947 m
CT4	1.5220	N/A	265.1009 m

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance ($^{\circ}\text{C}/\text{W}$)			
Junction to	Ambient	Case	Foot
RF1	5.8315	N/A	2.1411
RF2	19.4501	N/A	5.4075
RF3	16.2347	N/A	4.6545
RF4	43.3457	N/A	10.7409
Thermal Capacitance (Joules/ $^{\circ}\text{C}$)			
Junction to	Ambient	Case	Foot
CF1	4.0020 m	N/A	1.7111 m
CF2	24.2797 m	N/A	4.6651 m
CF3	280.8158 m	N/A	15.9435 m
CF4	1.4861	N/A	93.3125 m

Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002

